



P-Channel 20-V (D-S) MOSFET

PRODUCT SUMMARY					
V _{DS} (V)	$R_{DS(on)}\left(\Omega\right)$	I _D (A)			
	0.00875 at V _{GS} = - 4.5 V	- 14			
- 20	0.01075 at V _{GS} = - 2.5 V	- 12			
	0.0135 at V _{GS} = - 1.8 V	- 11			

FEATURES

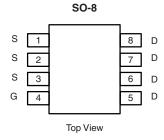
- Halogen-free Option Available
- TrenchFET® Power MOSFET



RoHS

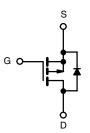
APPLICATIONS

- Game Station
 - Load Switch



Ordering Information: Si4421DY-T1-E3 (Lead (Pb)-free)

Si4421DY-T1-GE3 (Lead (Pb)-free and Halogen-free)



P-Channel MOSFET

ABSOLUTE MAXIMUM RATINGS T _A = 25 °C, unless otherwise noted						
Parameter	Symbol	10 s	Steady State	Unit		
Drain-Source Voltage		V_{DS}	- 20		V	
Gate-Source Voltage		V _{GS}	± 8			
Continuous Drain Current (T _{.I} = 150 °C) ^a	T _A = 25 °C	- I _D	- 14	- 10	A	
Continuous Diain Current (1) = 150 C)	T _A = 70 °C		- 11.5	- 8		
Pulsed Drain Current		I _{DM}	- 40		A	
Continuous Source Current (Diode Conduction) ^a		I _S	- 2.7	- 1.36		
Maximum Power Dissipation ^a	T _A = 25 °C	P _D	3.0	1.5	W	
Maximum Fower Dissipation	T _A = 70 °C		1.9	0.95		
Operating Junction and Storage Temperature Range	T _J , T _{stg}	- 55 to 150		°C		

THERMAL RESISTANCE RATINGS					
Parameter		Symbol	Typical	Maximum	Unit
Marrian Indiation to Ambient	t ≤ 10 s	R _{thJA}	33	42	°C/W
Maximum Junction-to-Ambient ^a	Steady State		70	85	
Maximum Junction-to-Foot (Drain)	Steady State	R _{thJF}	16	21	

Notes:

a. Surface Mounted on 1" x 1" FR4 board.

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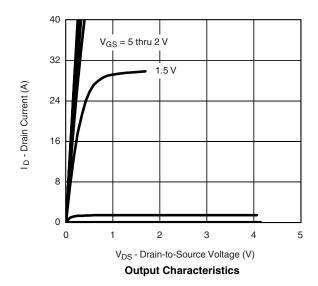
SPECIFICATIONS T _J = 25 °C, unless otherwise noted							
Parameter	Symbol	Test Conditions	Min.	Тур.	Max.	Unit	
Static							
Gate Threshold Voltage	V _{GS(th)}	$V_{DS} = V_{GS}, I_{D} = -850 \mu A$	- 0.4		- 0.8	V	
Gate-Body Leakage	I _{GSS}	$V_{DS} = 0 \text{ V}, V_{GS} = \pm 8 \text{ V}$			± 100	nA	
Zana Oata Wallana Busin Oamani	I _{DSS}	V _{DS} = - 20 V, V _{GS} = 0 V	V, V _{GS} = 0 V		- 1		
Zero Gate Voltage Drain Current		V_{DS} = - 20 V, V_{GS} = 0 V, T_{J} = 70 °C			- 10	μΑ	
On-State Drain Current ^a	I _{D(on)}	V _{DS} = - 5 V, V _{GS} = - 4.5 V	- 30			Α	
		V _{GS} = - 4.5 V, I _D = - 14 A		0.007	0.00875		
Drain-Source On-State Resistance ^a	R _{DS(on)}	V _{GS} = - 2.5 V, I _D = - 12 A		0.0085	0.01075	Ω	
		V _{GS} = - 1.8 V, I _D = - 11 A		0.011	0.0135	<u> </u>	
Forward Transconductance ^a	9 _{fs}	V _{DS} = - 10 V, I _D = - 14 A		55		S	
Diode Forward Voltage ^a	V_{SD}	I _S = - 2.7 A, V _{GS} = 0 V		- 0.6	- 1.1	V	
Dynamic ^b							
Total Gate Charge	Q_g			82	125		
Gate-Source Charge	Q _{gs}	$V_{DS} = -10 \text{ V}, V_{GS} = -4.5 \text{ V}, I_{D} = -14 \text{ A}$		10		nC	
Gate-Drain Charge	Q_{gd}			27			
Gate Resistance	R_g			3		Ω	
Turn-On Delay Time	t _{d(on)}			45	70		
Rise Time	t_r $V_{DD} = -10 \text{ V}, R_L = 10$	V_{DD} = - 10 V, R_L = 10 Ω		90	140	ns	
Turn-Off Delay Time		$I_D\cong$ - 1 A, V_{GEN} = - 4.5 V, R_G = 6 Ω		350	550		
Fall Time	t _f			170	260		
Source-Drain Reverse Recovery Time	t _{rr}	$I_F = -2.1 \text{ A}, dI/dt = 100 \text{ A/}\mu\text{s}$		135	210		

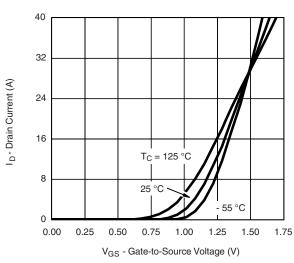
Notes:

- a. Pulse test; pulse width $\leq 300~\mu s,$ duty cycle $\leq 2~\%.$
- b. Guaranteed by design, not subject to production testing.

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted



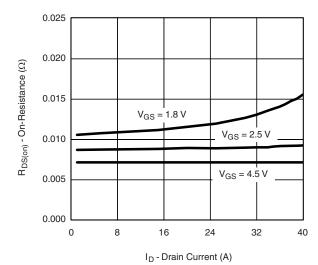


Transfer Characteristics

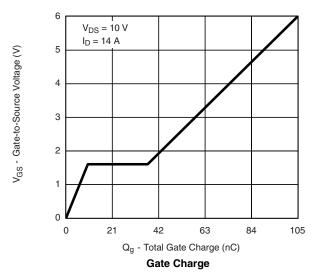


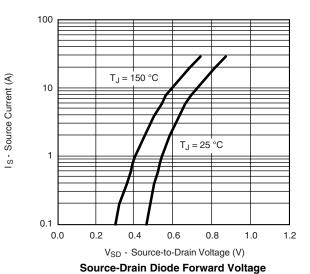


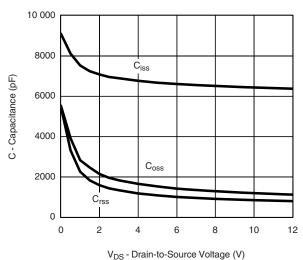
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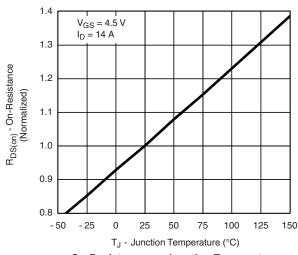
On-Resistance vs. Drain Current



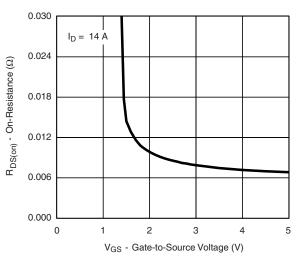




Capacitance



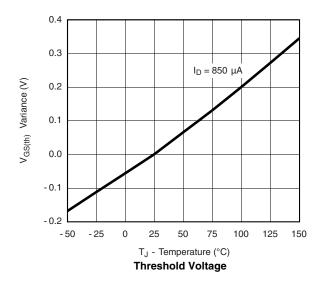
On-Resistance vs. Junction Temperature

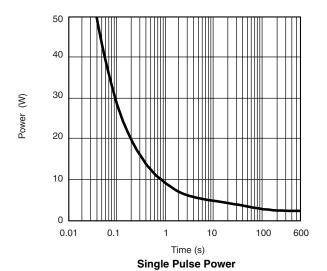


On-Resistance vs. Gate-to-Source Voltage

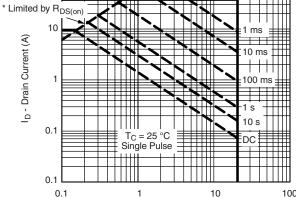
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TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted



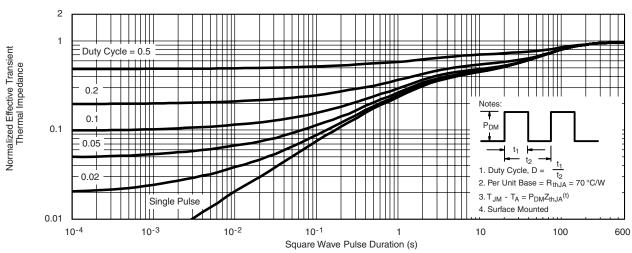


100



V_{DS} - Drain-to-Source Voltage (V) * V_{GS} > minimum V_{GS} at which $R_{DS(on)}$ is specified

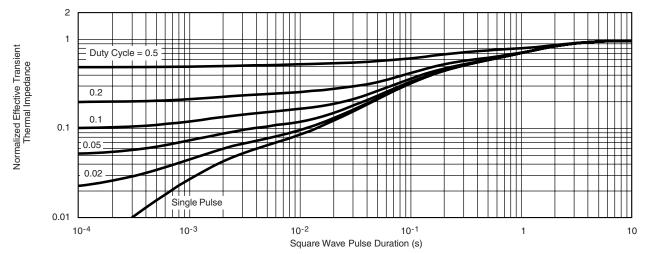
Safe Operating Area, Junction-to-Case



Normalized Thermal Transient Impedance, Junction-to-Ambient



TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted



Normalized Thermal Transient Impedance, Junction-to-Foot

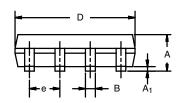
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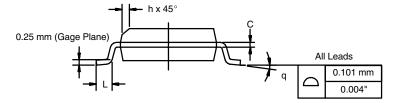
Document Number: 72114 S-82282-Rev. C, 22-Sep-08



SOIC (NARROW): 8-LEAD JEDEC Part Number: MS-012







	MILLIM	MILLIMETERS INCHES			
DIM	Min	Max	Min	Max	
Α	1.35	1.75	0.053	0.069	
A ₁	0.10	0.20	0.004	0.008	
В	0.35	0.51	0.014	0.020	
С	0.19	0.25	0.0075	0.010	
D	4.80	5.00	0.189	0.196	
Е	3.80	4.00	0.150	0.157	
е	1.27 BSC		0.050 BSC		
Н	5.80	6.20	0.228	0.244	
h	0.25	0.50	0.010	0.020	
L	0.50	0.93	0.020	0.037	
q	0°	8°	0°	8°	
S	0.44	0.64	0.018	0.026	
ECN: C-06527-Rev. I. 11-Sep-06					

DWG: 5498

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RECOMMENDED MINIMUM PADS FOR SO-8



Recommended Minimum Pads Dimensions in Inches/(mm)

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